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	Filing Date		2006-06-17	
	First Named Inventor	Tetsu	o Fujii	
	Art Unit		2815	
	Examiner Name	Jeron	ne Jackson, Jr.	
	Attorney Docket Number		30794.108-US-WO	

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	11	CN Office Action dated 5/18/2011, Patent Application No. 200910142642.4.					
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	9	Quality by Design: SemiLEDs. 2009, pgs. 1-4. http://www.semileds.com/Quality_by_Design_SemiLEDs.htm	n 🗆				

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